



# 18N25-HC

*Power MOSFET*

## 18A, 250V N-CHANNEL POWER MOSFET

■ DESCRIPTION

The UTC **18N25-HC** is a N-channel enhancement MOSFET using UTC's advanced technology to provide the customers with perfect  $R_{DS(ON)}$ , high switching speed, high current capacity and low gate charge.

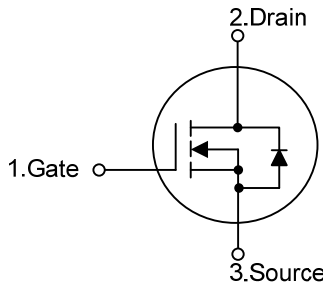
The UTC **18N25-HC** is universally applied in low voltage such as automotive, high efficiency switching for AC/DC converters and DC motor control, etc.

■ FEATURES

\*  $R_{DS(ON)} \leq 0.24 \Omega @ V_{GS}=10V, I_D=9.0A$

\* High Switching Speed

■ SYMBOL

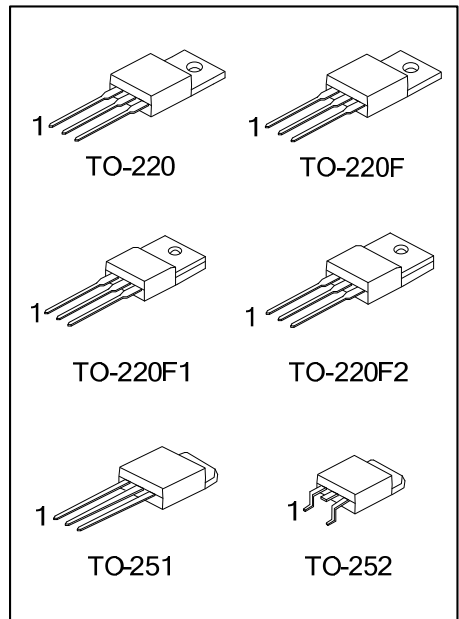


■ ORDERING INFORMATION

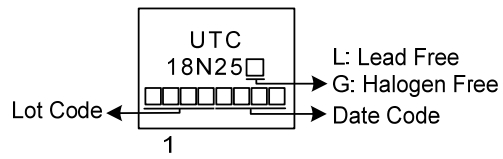
Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
18N25L-TA3-T	18N25G-TA3-T	TO-220	G	D	S	Tube
18N25L-TF1-T	18N25G-TF1-T	TO-220F1	G	D	S	Tube
18N25L-TF2-T	18N25G-TF2-T	TO-220F2	G	D	S	Tube
18N25L-TF3-T	18N25G-TF3-T	TO-220F	G	D	S	Tube
18N25L-TM3-T	18N25G-TM3-T	TO-251	G	D	S	Tube
18N25L-TN3-R	18N25G-TN3-R	TO-252	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>18N25G-TA3-T</p> <p>(1) Packing Type (2) Package Type (3) Green Package</p>	<p>(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TF3: TO-220F, TF1: TO-220F1, TF2: TO-220F2, TM3: TO-251, TN3: TO-252 (3) G: Halogen Free and Lead Free, L: Lead Free</p>
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■ 2MARKING



■ ABSOLUTE MAXIMUM RATINGS ( $T_A=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		$V_{DSS}$	250	V	
Gate-Source Voltage		$V_{GSS}$	$\pm 30$	V	
Continuous Drain Current	Continuous	$I_D$	$T_C=25^\circ\text{C}$	18	A
			$T_C=100^\circ\text{C}$	10.8	A
Pulsed		$I_{DM}$	36	A	
Single Pulsed Avalanche Current		$I_{AS}$	3.6	A	
Single Pulsed Avalanche Energy		$E_{AS}$	194	mJ	
Power Dissipation	TO-220	$P_D$	98	W	
	TO-220F/TO-220F1		36	W	
	TO-220F2				
	TO-251/TO-252		54	W	
Junction Temperature		$T_J$	+150	$^\circ\text{C}$	
Storage Temperature		$T_{STG}$	-55 ~ +150	$^\circ\text{C}$	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3.  $L=30\text{mH}$ ,  $I_{AS}=3.6\text{A}$ ,  $V_{DD}=50\text{V}$ ,  $R_G=25\Omega$ , Starting  $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F	$\theta_{JA}$	62.5	$^\circ\text{C/W}$
	TO-220F1/TO-220F2			
	TO-251/TO-252			
Junction to Case	TO-220	$\theta_{JC}$	1.27	$^\circ\text{C/W}$
	TO-220F/TO-220F1		3.47	$^\circ\text{C/W}$
	TO-220F2			
	TO-251/TO-252		2.31 (Note)	$^\circ\text{C/W}$

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

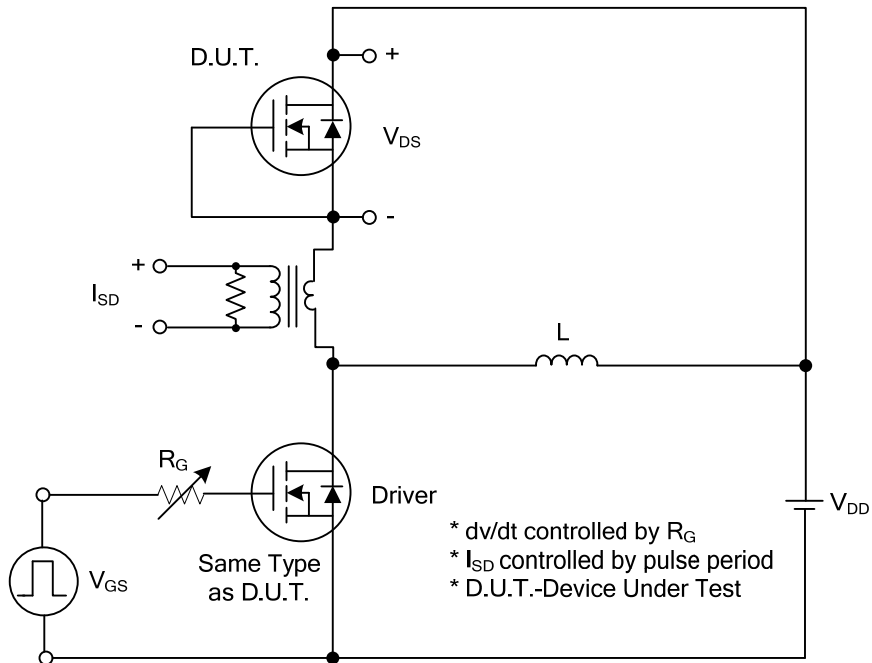
■ ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D=250\mu A, V_{GS}=0V$	250			V
Drain-Source Leakage Current	$I_{DSS}$	$V_{DS}=250V, V_{GS}=0V$			10	$\mu A$
Gate-Source Leakage Current	Forward	$V_{GS}=+30V, V_{DS}=0V$			+100	nA
	Reverse	$V_{GS}=-30V, V_{DS}=0V$			-100	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=9.0A$			0.24	$\Omega$
<b>DYNAMIC PARAMETERS</b>						
Input Capacitance	$C_{ISS}$	$V_{GS}=0V, V_{DS}=25V, f=1.0MHz$		870		pF
Output Capacitance	$C_{OSS}$			135		pF
Reverse Transfer Capacitance	$C_{RSS}$			8.8		pF
<b>SWITCHING PARAMETERS</b>						
Total Gate Charge	$Q_G$	$V_{DS}=200V, V_{GS}=10V, I_D=18A$ $I_G=1mA$ (Note 1, 2)		25		nC
Gate to Source Charge	$Q_{GS}$			8.2		nC
Gate to Drain Charge	$Q_{GD}$			7		nC
Turn-ON Delay Time	$t_{D(ON)}$	$V_{DS}=100V, V_{GS}=10V, I_D=18A,$ $R_G=25\Omega$ (Note 1, 2)		9		ns
Rise Time	$t_R$			18		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			55		ns
Fall-Time	$t_F$			22		ns
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Maximum Body-Diode Continuous Current	$I_S$				18	A
Maximum Body-Diode Pulsed Current	$I_{SM}$				36	A
Drain-Source Diode Forward Voltage	$V_{SD}$	$I_S=18A, V_{GS}=0V$			1.4	V
Body Diode Reverse Recovery Time	$t_{rr}$	$I_S=18A, V_{GS}=0V, di_F/dt=100A/\mu s$ (Note 1)		160		ns
Reverse Recovery Charge	$Q_{rr}$				2	

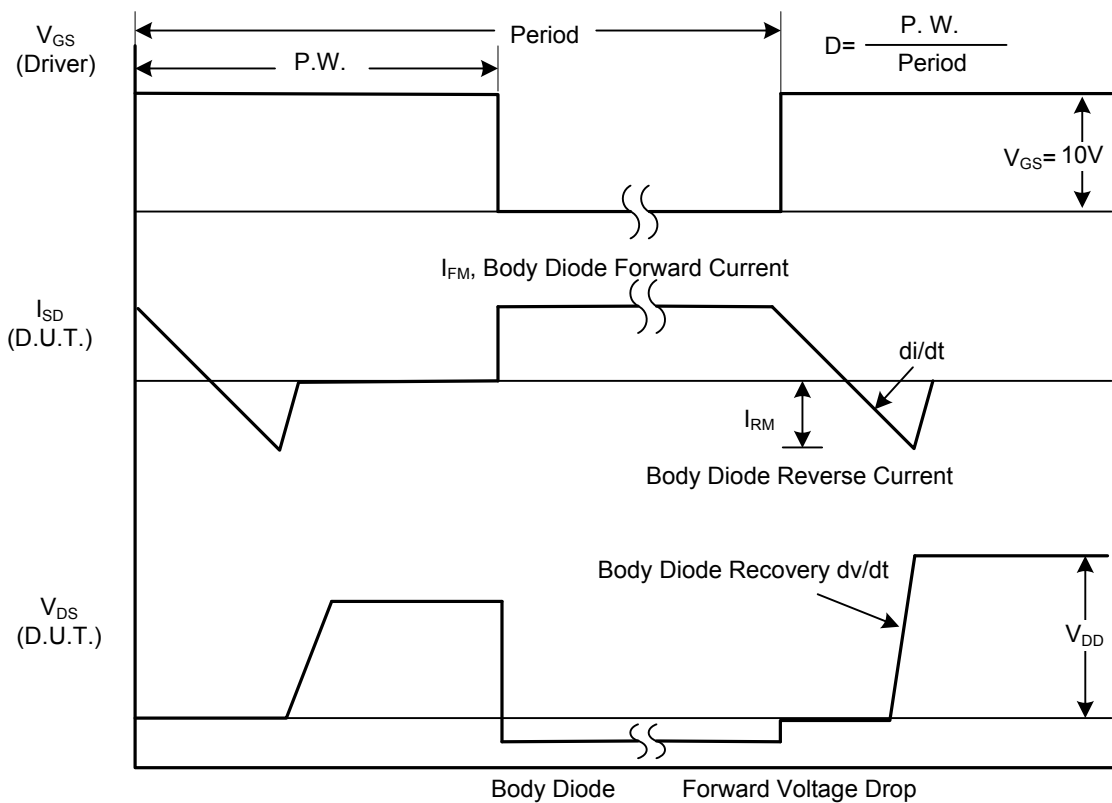
Notes: 1. Pulse Test: Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .

2. Essentially independent of operating temperature.

## TEST CIRCUITS AND WAVEFORMS

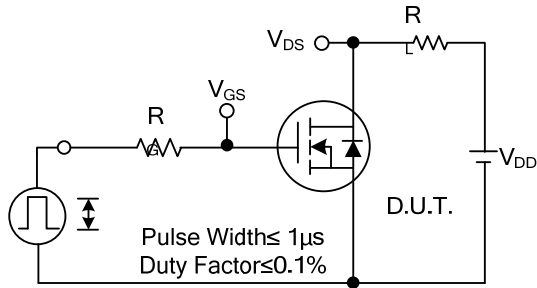


**Peak Diode Recovery  $dv/dt$  Test Circuit**

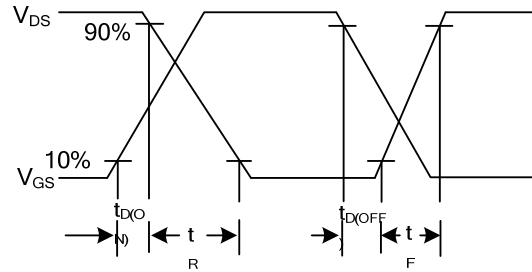


**Peak Diode Recovery  $dv/dt$  Waveforms**

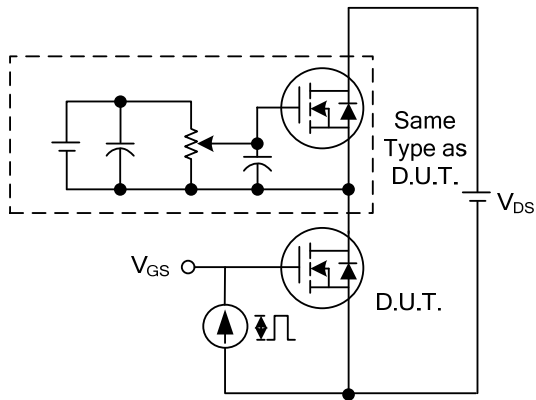
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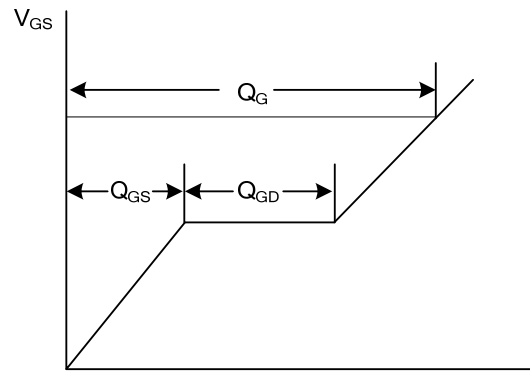
Switching Test Circuit



Switching Waveforms

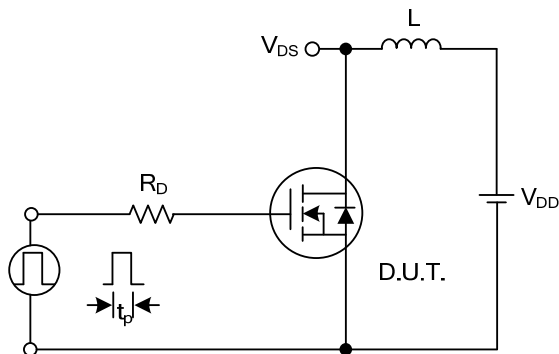


Gate Charge Test Circuit

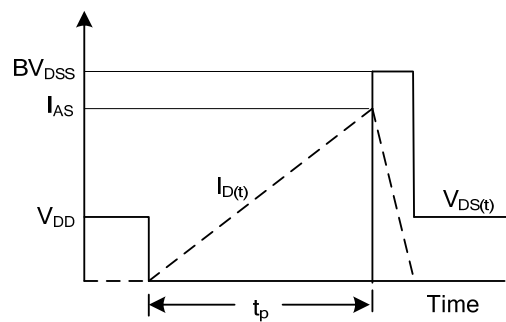


Charge

Gate Charge Waveform

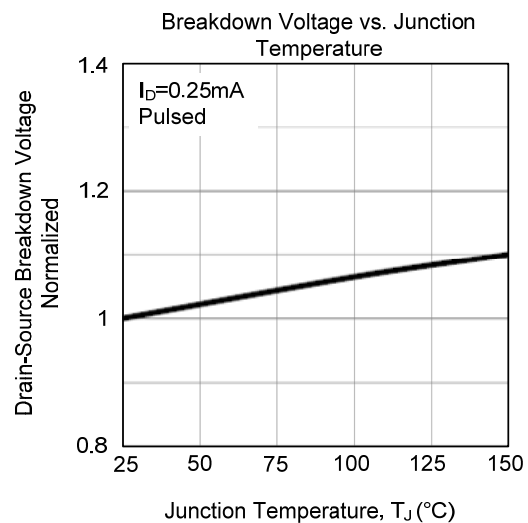
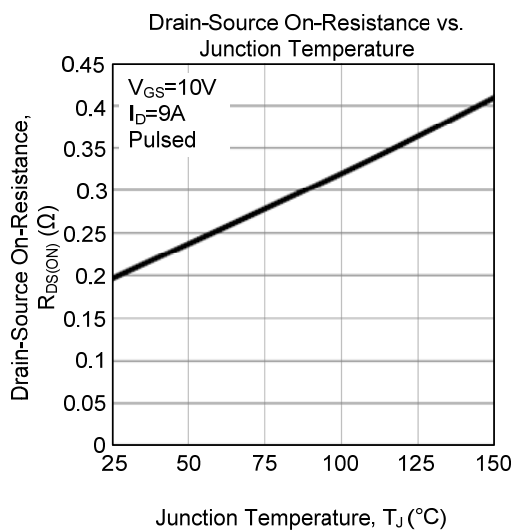
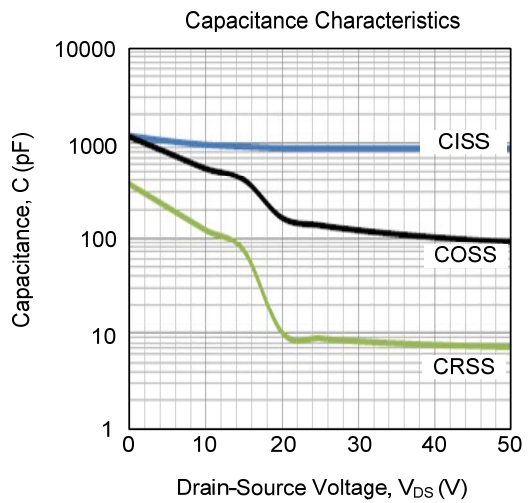
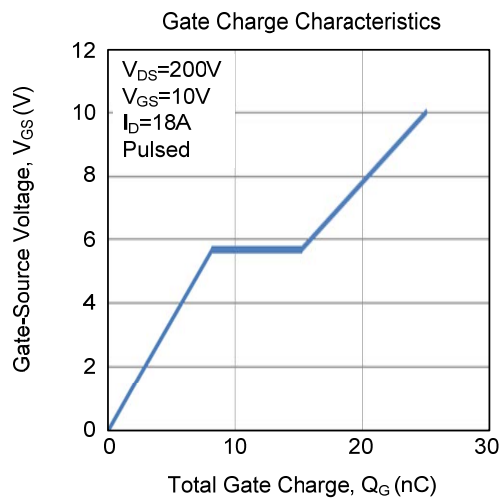
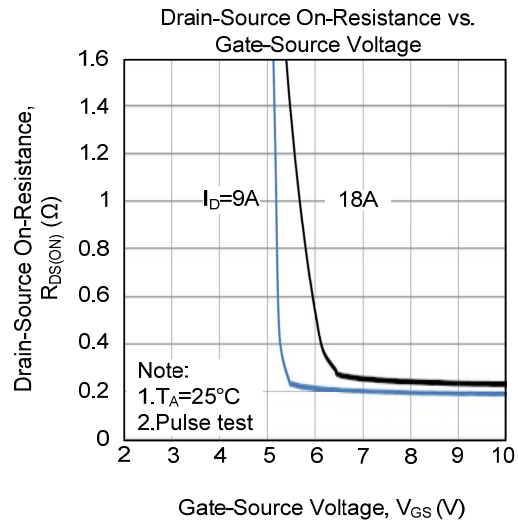
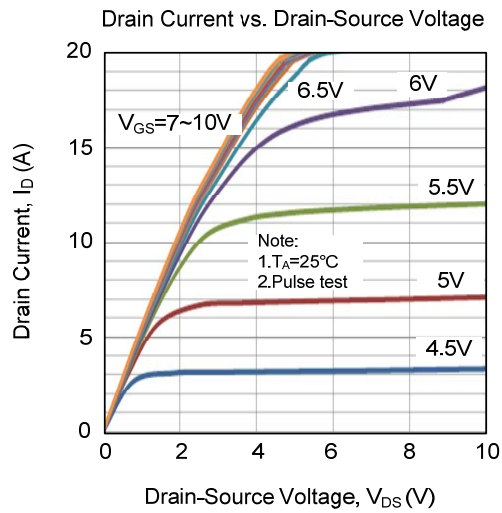


Unclamped Inductive Switching Test Circuit

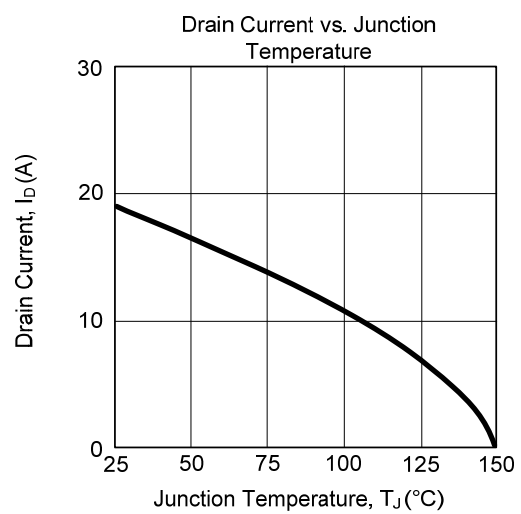
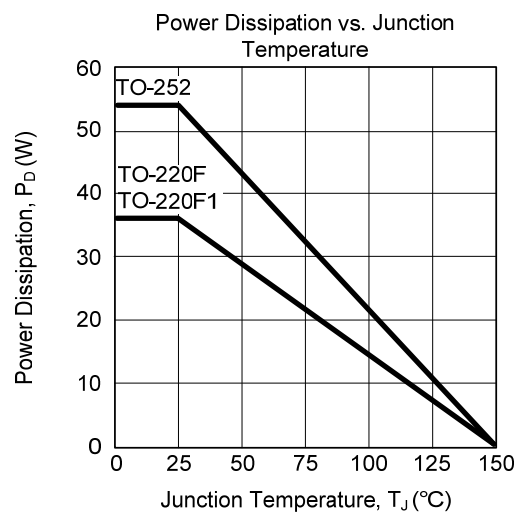
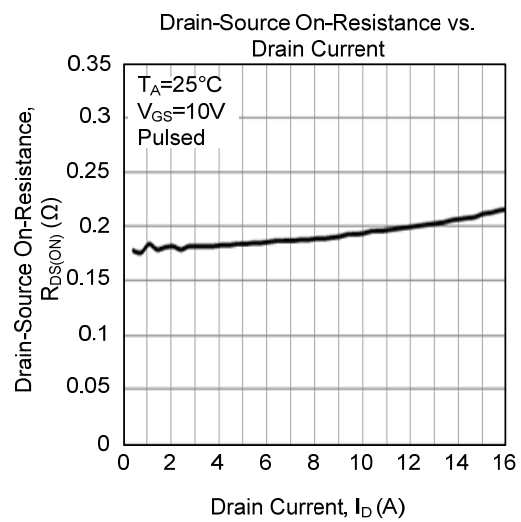
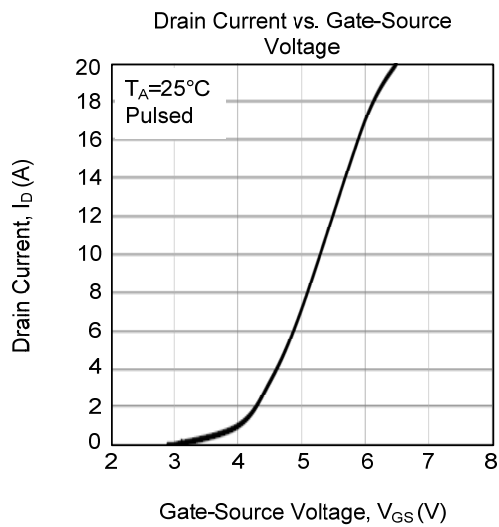
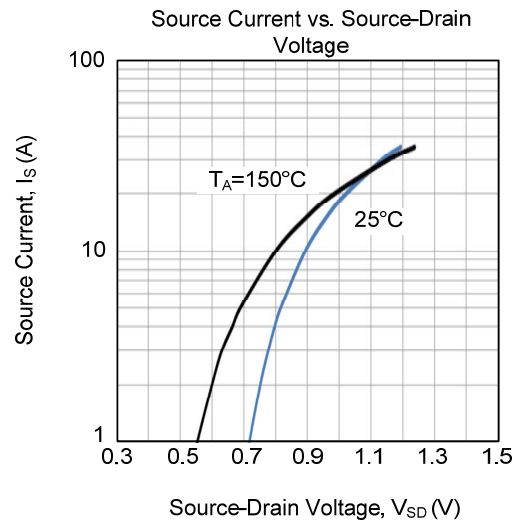
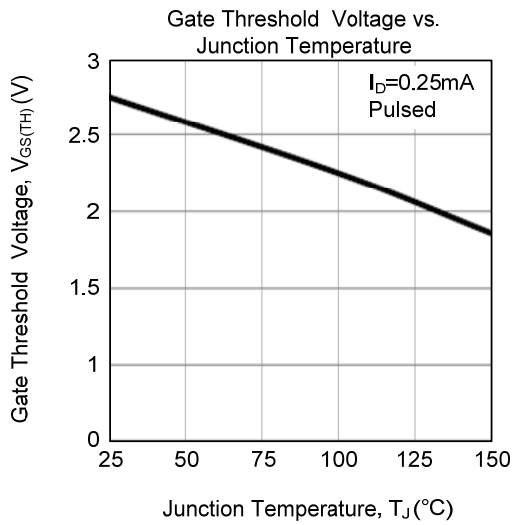


Unclamped Inductive Switching Waveforms

## TYPICAL CHARACTERISTICS

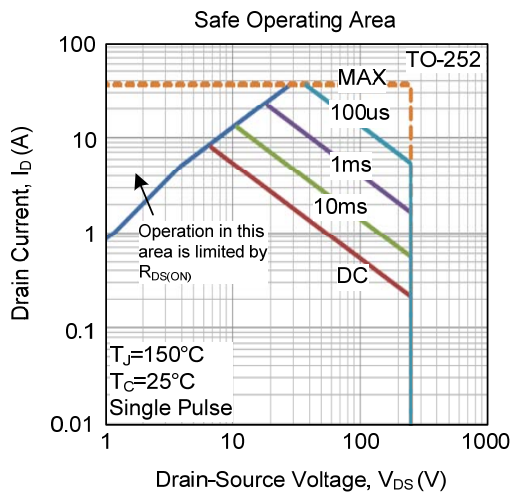


### ■ TYPICAL CHARACTERISTICS (Cont.)





■ TYPICAL CHARACTERISTICS (Cont.)



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